

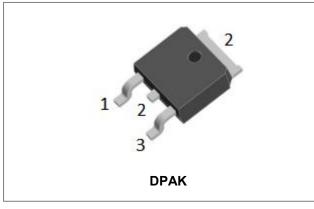
Data Sheet N0798, Rev. A

**Technical Data** 

## MBRD360 THRU MBRD3200

# RoHS 🗭

## MBRD360 THRU MBRD3200 SCHOTTKY RECTIFIER



#### Features

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- "-A" is an AEC-Q101 qualified device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Applications

- Disk drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

#### Maximum Ratings and Electrical characteristics @T<sub>A</sub> = 25°C unless otherwise specified

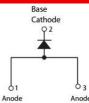
Characteristics	Symbol	MBRD 360	MBRD 380	MBRD 3100	MBRD 3150	MBRD 3200	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> VR	60	80	100	150	200	v
Average Forward Current	I <sub>F(AV)</sub>	3		Α			
Max. Peak One Cycle Non-Repetitive Surge Current(8.3ms Single half sine-wave)	I <sub>FSM</sub>	80		А			
Max. Forward Voltage Drop* @3A, 25°C	VF	0.65	0.75	0.85	0.90	0.92	V
Max. Reverse Current* @V <sub>RWM</sub> , 25°C	I <sub>R</sub>			1			mA
Max. Junction Capacitance(Note1)	Ст		250		1(	00	pF
Junction Temperature	TJ	-55 to +150		°C			
Storage Temperature	T <sub>stg</sub>	-55 to +150		°C			
Typical Thermal Resistance Junction to Case (DC operation)	$R_{ ext{ heta}JC}$			6.0			°C/W
Approximate Weight	wt			0.39			g
Case Style		DPAK					

\* Pulse width < 300 µs, duty cycle < 2%

Note1: Measured at 1.0 MHz and applied reverse voltage of 5.0V D.C.

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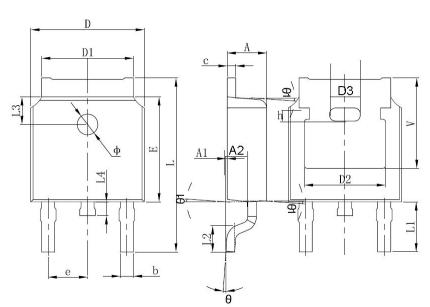
#### **Circuit Diagram**





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## **Mechanical Dimensions DPAK**



	Millim	neters	Inches		
SYMBOL	Min.	Max.	Min.	Max.	
A	2.20	2.40	0.087	0.094	
A1	0.00	0.127	0.000	0.005	
b	0.66	0.86	0.026	0.034	
С	0.46	0.60	0.018	0.024	
D	6.50	6.70	0.256	0.264	
D1	5.13	5.46	0.202	0.215	
D2	4.83 REF.		0.190 REF.		
E	6.00	6.20	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.70	10.40	0.381	0.409	
L1	2.90 REF.		0.144 REF.		
L2	1.40	1.70	0.055	0.067	
L3	1.60 REF.		0.063 REF.		
L4	0.60	1.00	0.024	0.039	
Φ	1.10	1.30	0.043	0.051	
Θ	0°	8°	0°	8°	
h	0.00	0.30	0.000	0.012	
V	5.35 REF.		0.211 REF.		

First row: Part Number (MBRD360, MBRD380, MBRD3100, MBRD3150,

YY is the manufacture year, WW is the manufacture week code,

Second row: SSG YYWWL

L is the wafer's Lot Number

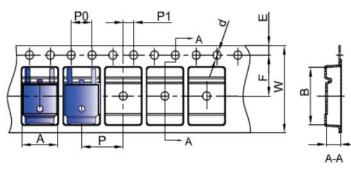
MBRD3200)

## **Ordering Information**

Device	Package	Shipping
MBRD360 THRU MBRD3200	DPAK (Pb-Free)	2500pcs / reel
MBRD360TR THRU MBRD3200TR	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

#### **Carrier Tape Specification DPAK**



SYMBOL	Millimeters			
	Min.	Max.		
А	6.80	7.00		
В	10.40	10.60		
С	2.60	2.80		
d	Φ1.45	Φ1.65		
E	1.65	1.85		
F	7.40	7.60		
P0	3.90	4.10		
P	7.90	8.10		
P1	1.90	2.10		
W	15.90	16.30		

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W

**Marking Diagram** 

Part Number

SSG YYWWL

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### MBRD360 THRU MBRD3200



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